

SIC SCHOTTKY DIODE TYPE 2×50A

Features

- High surge current capable
- Zero reverse recovery current · VDC
- High bandwidth
- Isolation type package

Benefits

- Unipolar rectifier
- Zero switching loss
- Higher efficiency

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment

- Temperature Independent Switching Behavior
 - VDC 650 V
- IF (Tc<135°C) 2×50 A
- Smaller heat sink
- Parallel devices without thermal runaway
- Power factor correction
- Diode snubber
- Automotive
- induction heating

Maximum Ratings

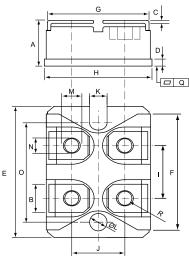
Operating Junction Temperature : - 55 $^\circ$ C to +175 $^\circ$ C

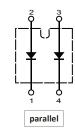
Storage Temperature : -55 $^\circ\!C$ to +175 $^\circ\!C$

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×50-065P3B	650V	650V

Maximum Rating	Symbol	mbol Conditions		Unit	
Continuous forward current (per diode)	I _F	T _C =135 °C	50		
Surge non-repetitive forward current	I _{FSM}	T _C =25 °C, t _p =8.3 ms	400		
sine halfwave (per diode)	'FSM	T _C =150 °C, t _p =8.3 ms	250	А	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μ s	1600		
(per diode)		T _C =150 °C, t _p =10 μ s	1000		
Repetitive peak reverse voltage V _{RRM}		T _j =25 °C	650	V	
Isolation voltage between All Terminals and Baseplate	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA	2500	V	
Mounting torque		To heatsink	1.3	Nm	
		To terminal	1.1		







DIMENSIONS					
	INC	HES	N	IM	
	MIN	MAX	MIN	MAX	
Α	0.460	0.483	11.68	12.28	
В	0.307	0.323	7.80	8.20	
С	0.030	0.033	0.75	0.85	
D	0.071	0.081	1.80	2.05	
Е	1.488	1.504	37.80	38.20	
F	1.248	1.260	31.70	32.00	
G	0.917	0.957	23.30	24.30	
Н	0.996	1.008	25.30	25.60	
Ι	0.579	0.602	14.70	15.30	
J	0.492	0.516	12.50	13.10	
К	0.161	0.169	4.10	4.30	
L	0.161	0.169	4.10	4.30	
М	0.181	0.197	4.60	5.00	
Ν	0.165	0.181	4.20	4.60	
0	1.181	1.197	30.00	30.40	
Q	-0.002	0.004	-0.05	0.10	
R	M4*8				

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Electrical Characteristics, at T_j=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}		650	-	-	
Diode forward voltage	V _F	I _F =50A, T _j =25 °C	-	1.50	1.70	V
		I _F =50A, T _j =175 °C	-	1.70	2.00	
Reverse current	I _R	V _R =650V, T _j =25 °C	-	30	60	μΑ
		V _R =650V, T _j =175 °C	-	60	250	

AC Characteristics (per diode)

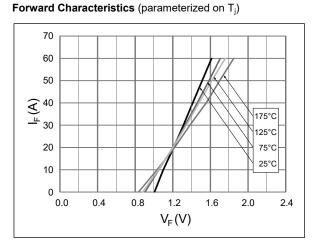
Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R =400V, T _j =25 °C	-	68	-	nC
Total capacitance	С	V _R =1V, f=1 MHz T _j =25 °C	-	2105	-	pF
		V _R =200V, f=1 MHz T _j =25 °C	-	240	-	
		V _R =400V, f=1 MHz T _j =25 °C	-	183	-	

Thermal Characteristics (per diode)

Static Characteristics	Sumbol	Values		Ī
	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta JC}$	0.28	°C/W	Ī



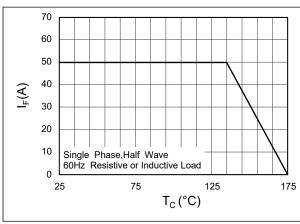
Typical Performance



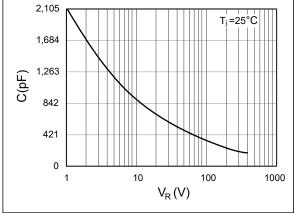
1.0 175°C 125°0 0.1 75 I_R(mA) 25 0.01 0 0 10 20 30 40 50 60 70 80 90 100 Volts (%)

Reverse Characteristics (parameterized on Tj)

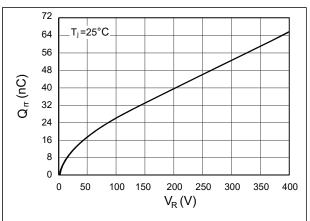




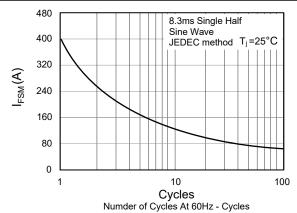
Capacitance



Recovery Charge







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